NSN 5961-01-350-2082

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-350-2082 **Inclosure Material:** Metal **Overall Length:** 0.013 inches **Overall Height:** Between 0.005 inches and 0.008 inches **Overall Width:** 0.013 inches **Mounting Method:** Compression Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes forward current, average outside diameter **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius junction **Precious Material:** Gold **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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